

Reference Module - Industrial Series

The Industrial Series utilizes Seoul's flagship high efficacy 5630 LEDs to deliver efficacies up to 194 Lm/W at typical driving currents with typical flux values of 9700 lumens. This solution features uniformity of light and color and enables easy installation with a Zhaga compatible mounting pattern.

Applications:















Features:

- High efficacy, long life
- Industry standard mechanical attributes
- Optimized for industry standard power supplies
- 3 SDCM
- ROHS Compliant
- Both 560mm and 1120mm lengths avilable

Key Applications:

- Troffer Retrofit
- High Bay
- LED Panel
- Channel

Product Selection: SMJD-3624144B-XXN1 I_F = 660mA, T_c = 25°C

ССТ	CDI	Fl	ux	Dimension	Order Code		
CCT	CRI	Min.	Тур.	Difficusion	Order Code		
3000		3950	4250		SMJD-3624144B-XXN100E25G038All		
3500	- 80	3930				- 560*20	SMJD-3624144B-XXN100E25F038All
4000	- 80 -		4040		560 20	SMJD-3624144B-XXN100E35E038All	
5000		4040	4350		SMJD-3624144B-XXN100E35C038AII		

Product Selection: SMJD-4253182B-XXN1 $I_F = 1300 \text{mA}$, $T_c = 25^{\circ}\text{C}$

ССТ	CRI	FI	ux	Dimension	Order Code	
CCI	CKI	Min.	Тур.	Diffictision	Order Code	
3000		8790	9450	1120*20	SMJD-4253182B-XXN100J45G038All	
3500	 80	8790	9430		SMJD-4253182B-XXN100J45F038All	
4000		0020		1120 20	SMJD-4253182B-XXN100J70E038AII	
5000		9020 97	9700		SMJD-4253182B-XXN100J70C038All	



Electro Optical Characteristics: SMJD-3624144B-XXN1 $I_F = 660 \text{mA}$, $T_c = 25^{\circ}\text{C}$

Dawamatau	Symbol	Value			l lade	Damada
Parameter		Min.	Тур.	Max.	Unit	Remark
Luminous Flux	Φ _V ^[2]	3950	4250	-	- lm	F,G
Luillillous Flux	Ψ_{V} i-s	4040	4350	-	- 1111	C,E
		4745	5028	5311		С
Correlated Color	ССТ	3710	3985	4260	K	E
Temperature [3]		3200	3500	3700		F
		2870	3045	3220		G
CRI	Ra	80	-	-	-	-
Input Voltage	V _F	32.8	34	35.2	V _{DC}	@660m A
Power Consumption	Р	21.6	22.4	23.2	W	@660mA
Efficiency	I DW	-	189	-	I m /\\/	F,G
Linciency	LPW -	-	194	-	- Lm/W	C,E

Electro Optical Characteristics: SMJD-4253182B-XXN1 $I_F = 1300 \text{mA}, T_c = 25^{\circ}\text{C}$

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Parameter	Symbol	Min.	Тур.	Max.	Unit	Remark
Luminous Flux	Φ _V [2]	8790	9450	-	- lm	F,G
Luminous Flux	Ψ_{V}^{i-j}	9020	9700	-	- 1111	C,E
		4745	5028	5311		С
Correlated Color	ССТ	3710	3985	4260	К	E
Temperature [3]		3200	3500	3700		F
		2870	3045	3220		G
CRI	Ra	80	-	-	-	-
Input Voltage	V_{F}	40	41.5	43	V_{DC}	@4200 4
Power Consumption	Р	52	54	55.9	W	@1300mA
Efficiency	LPW	-	175	-	l m /\\/	F,G
Linciency	LPVV	-	180	-	- Lm/W	C,E

Notes:

- 1 Above data tested with constant typical current at T_c =25 °C.
- 2 Φ_{v} is the total luminous flux output measured with an integrated sphere.
- 3 Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
- 4 To use the module properly, recommend to drive the module by a Constant Current Source (CCS). But the Maximum output voltage of the CCS should be limited by referring this sheet.

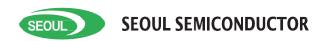


Absolute Maximum Operating Specification: $T_c = 25^{\circ}C$

Model	Parameter	Symbol	Unit	Value	Remark
	Power Consumption	Р	W	62	
SMJD-3624144B-XXN1	Forward Voltage	V_{F}	V	37.3	
	Driving Current (2)	${ m I}_{\sf F}$	mA	1650	
	Power Consumption	Р	W	79	
SMJD-4253182B-XXN1	Forward Voltage	V_{F}	V	43.5	
	Driving Current (2)	${ m I}_{\sf F}$	mA	1820	
	Operating Temperature (3)	T _C	oC	- 40 ~ 85	Reference point
	Storage Temperature	T_{stg}	oC	- 40 ~ 100	With no power
All	Thermal resistance	D	°C/W	0.3	
All	(T _C to base)	$R_{th(Tc\text{-}base)}$	°C/ VV	0.5	
	ECD Consitivity		I/V	±8	IEC Air
	ESD Sensitivity	-	KV	±4	HBM

Notes:

- 1 Above data tested with constant typical current at T_c =25 °C.
- 2 $\Phi_{\text{\tiny V}}$ is the total luminous flux output measured with an integrated sphere.
- 3 Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram.
- 4 To use the module properly, recommend to drive the module by a Constant Current Source (CCS). But the Maximum output voltage of the CCS should be limited by referring this sheet.



Notes:

*Colors fully compliant with the CIE requested color temperatures on the following table:

Correlated Color Temperature	Nominal CCT	CCT (K)
С	5000 K	5028 ± 283
E	4000 K	3985 ±275
F	3500 K	3465 ± 245
G	3000 K	3045 ±175

Illustration: How to predict components temperature



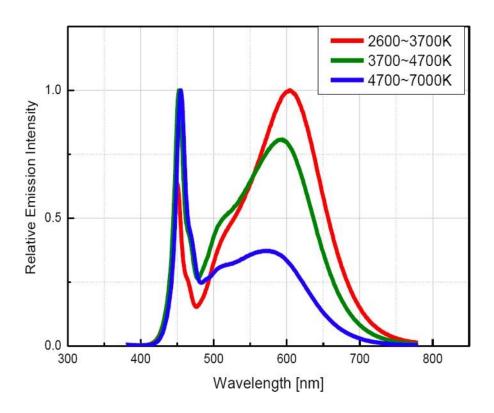
*Recommended Tc Testing point

Notes:

- 1 The modules must be operated within the operating conditions stated in the Absolute Maximum Operating Specifications.
- 2 For SMJD-3624144B-XXN1, please use a Constant Current Source (CCS) to drive the module, the typical V_F of module is 34 VDC and V_{F_MAX} is 35.2 V_{DC} , respectively.
- 3 For SMJD-4253182B-XXN1, please use a Constant Current Source (CCS) to drive the module, the typical V_{FO} module is 41.5VDC and V_{FDMX} is 43 V_{DC} , respectively.
- 4 Operating temperature was tested at the assigned Tc point on the PCB.
- 5 To ensure the module works properly, Tc should refer to "Absolute Maximum Operating Specification".

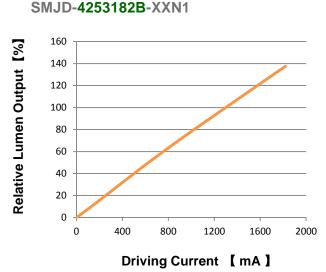
Relative Spectral Distribution

• Relative Spectral Distribution vs. Wavelength

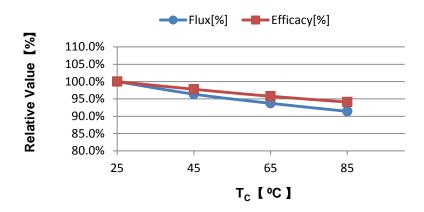


• Scale ratio curve for related lumen output VS driving current, $T_c = 25$ °C



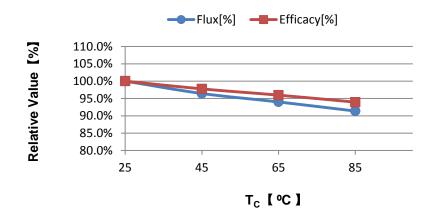


Flux and Efficacy Versus Temperature at $T_C(at I_F nominal)$ SMJD-3624144B-XXN1, $I_F = 660 mA$



T _C [°C]	Flux[%]	Efficacy[%]
25	100	100
45	96.4	97.8
65	93.7	95.8
85	91.4	94.1

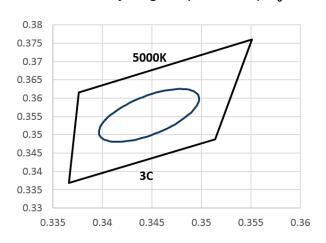
Flux and Efficacy Versus Temperature at $T_C(at\ I_F\ nominal)$ SMJD-4253182B-XXN1, $I_F=1300mA$



Flux[%]	Efficacy[%]
100	100
96.4	97.8
94.0	96.0
91.4	93.9
	100 96.4 94.0

Color Bin Structure

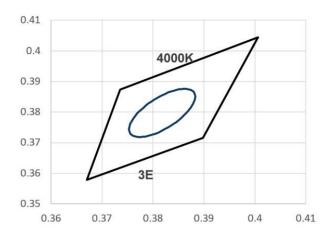
CIE Chromaticity Diagram (Cool white), $T_c = 25$ °C



5000K 3 Step Ellipse

3C						
х	у	а	b	theta		
0.3447	0.3553	0.0081	0.0035	60		

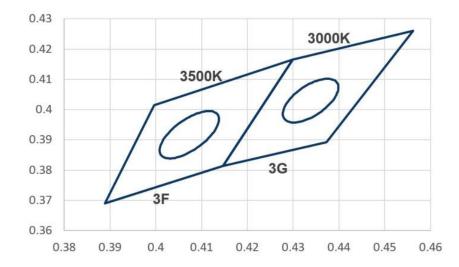
CIE Chromaticity Diagram (Nature white), $T_c = 25$ °C



4000K 3 Step Ellipse

3E							
	x	у	а	b	theta		
	0.3818	0.3797	0.0094	0.004	53		

CIE Chromaticity Diagram (Warm white), $T_c = 25$ °C



3500K 3 Step Ellipse

		3F		
x	у	а	b	theta
0.4073	0.3917	0.0093	0.0041	53

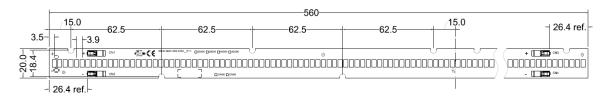
3000K 3 Step Ellipse

		3 G		
x	у	а	b	theta
0.4338	0.4030	0.0085	0.0041	53



Mechanical Dimensions

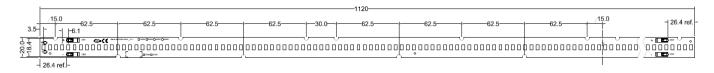
SMJD-3624144B-XXN1





Dimension	Specification	Tolerance	Unit
Module Length	560	±0.5	
Module Width	20	±0.3	mm
Module Height	5.5	±0.3	111111
PCB Thickness	1	±0.1	

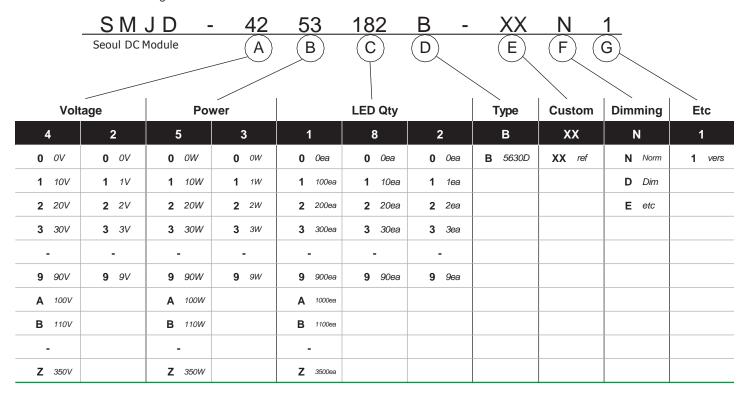
SMJD-4253182B-XXN1



Dimension	Specification	Tolerance	Unit
Module Length	1120	±0.6	
Module Width	20	±0.3	mm
Module Height	5.5	±0.3	111111
PCB Thickness	1	±0.1	

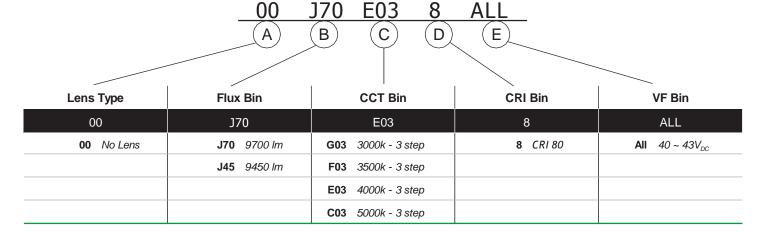
Product Nomenclature:

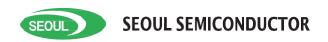
*Please refer to the following chart



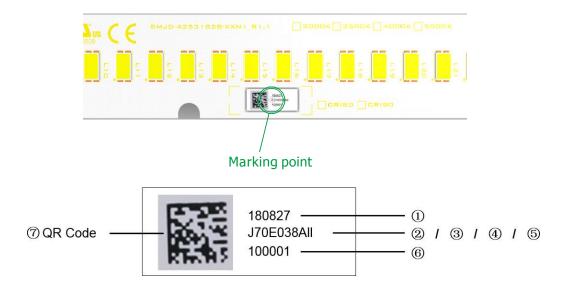
Product Nomenclature: Binning

*Please refer to the following chart





Marking Information



No.	Item	Information	Digits	Remark
1	Date	YYMMDD	6 Digit	SMT date
2	Flux ⁽¹⁾	J70	3 Digit	J70=9700lm
3	CCT	X03 3-step Mixing	3 Digit	X=C,E,F,G
4	CRI	8	1 Digit	CRI=80
(5)	V_{F}	All	3 Digit	
6	Lot No.	1	1 Digit	0~9,A~Z
•	Sequence No.	00001	5 Digit	00001 ~99999
7	QR Code	QR Code	-	Please refer to below table

Note:

*Flux Bin - please refer to following chart for definitions:

Flux Bin Definitions

Symbol	lm	Symbol	lm	Symbol	lm	Symbol	lm
A50	500	D50	3500	G50	6500	J50	9500
B50	1500	E50	4500	H50	7500	K20	10200
C50	2500	F50	5500	150	8500	L00	11000



Module QR Code Information

QR Code Information								
Items	Items Factory SAP Code SMT Date MP Information Line No. Lot No. Product Note							Note
Digits	1 Digit	7 Digits	6 Digits	10 Digits	1 Digit	1 Digit	5 Digits	In Total 31
Information	*	*****	YYMMDD	J70E03 8ALL	1~9, A~Z	1~9, A~Z	00001	Digits

Notes:

- 1 QR coded information shall include the fields described in the table above.
- 2 Minimum size of QR code shall be 4.5 mm x 4.5 mm and a minimum QR codegrade of 'C'.

 *'A' grading is preferred.
- 3 If the component is small to have a full label, it is acceptable to have only the QR code in minimum size of 6 mm by 6 mm printed on a label.
- 4 QR Code Example: ******180827J70E038ALL11100001

Label Information

PO Number	XXXXXX(1)
Supplier Part Number	SMJD-4253182B-XXN100J70E038AII ⁽²⁾
Bin Code	J70E038AII ⁽³⁾
Quantity	XX IIII II IIII III
Country of Origin	XX ⁽⁴⁾
Date Code	YYYYWW (5)
Lot Code	YYMDDXXXXX- XXXXXXX(6)
SEOUL	SEOUL SEMICONDUCTOR CO.,LTD.

Notes:

[1] This is customer's PO Number

[2] Please refer to SPEC page 9 (30 digit code)

[3] Please refer to SPEC page 9

[4] Country of Origin: 2 digit code . For example : Chinese Code: CN

[5] Date Code: YYYYWW: Packing Date: Year + Week

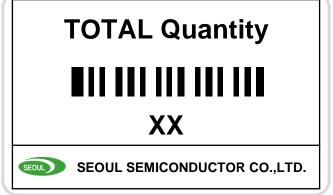
[6] Lot Code:

Initial of manufacture is refer to the 2D code rule.

YYMDD: Packing Date (Oct.: A, Nov.: B, Dec.: C)

X : Initial of Manufacturer XXXX : Sealing Pack No. XXXXXXX : SSC SAP Code

[7] It is attached to the top left corner of the box.

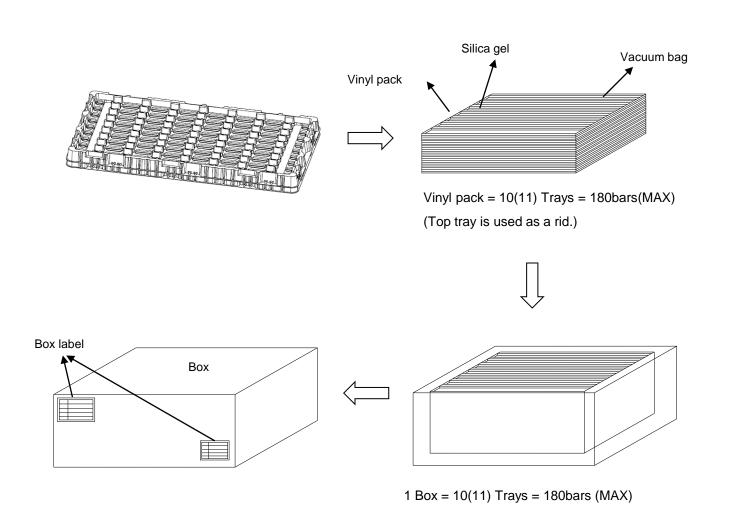


Notes:

[1] Attached to the bottom right corner of the carton box.

Packaging Specification

Model	Tray		Box		Pallet	
	Size(mm)	Q'ty per Tray	Size(mm)	Q'ty per Box	Size(mm)	Q'ty per Pallet
SMJD-3624144B-XXN1	610 x 300 x 30	18	625*315*215	180	1000*1000	3600
SMJD-4253182B-XXN1	1230 x 285 x 30	16	1245*300*133	80	1300*1100	1920





Storage before use

- 1. When storing devices for a long period of time before usage, please following these guidelines.
 - The devices should be stored in the anti-static bag that itwas shipped in from Seoul-Semiconductor with opening
 - If the anti-static bag has been opened, re-seal preventing air and moisture from being present in the bag.



Company Information

Seoul Semiconductor (SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotice, general illumination/ lighting, appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", deep UV LEDs, "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology", a proprietary family of high-voltage LEDs. The company's broad product portfolio includes a wide array of package and device choices such as Acrich, high-brightness LEDs, mid-power LEDs, side-view LEDs, through-hole type LED lamps, custom displays, and sensors. The company is vertically integrated from epitaxial growth and chip manufacture in it's fully owned subsidary, Seoul Viosys, through packaged LEDs and LED modules in three Seoul Semiconductor manufacturing facilities. Seoul Viosys also manufactures a wide range of unique deep-UV wavelength devices.

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